Preferred Devices

Complementary Power Transistors

D²PAK for Surface Mount

Complementary power transistors are for general purpose power amplification and switching such as output or driver stages in applications such as switching regulators, converters and power amplifiers.

Features

- Low Collector–Emitter Saturation Voltage V_{CE(sat)} = 1.0 V (Max) @ 8.0 A
- Fast Switching Speeds
- Complementary Pairs Simplifies Designs
- Epoxy Meets UL 94 V-0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B > 8000 V Machine Model, C > 400 V
- Pb-Free Packages are Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	80	Vdc
Emitter-Base Voltage	V _{EB}	5	Vdc
Collector Current – Continuous – Peak	I _C	10 20	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	50 1.67	W W/°C
Total Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	2.0 0.016	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to 150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.5	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	75	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



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SILICON POWER TRANSISTORS 10 AMPERES, 80 VOLTS, 50 WATTS

> MARKING DIAGRAM



D²PAK CASE 418B STYLE 1



= 4 or 5

A = Assembly Location

= Year

VW = Work Week

= Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]
MJB44H11	D ² PAK	50 Units/Rail
MJB44H11G	D ² PAK (Pb-Free)	50 Units/Rail
MJB44H11T4	D ² PAK	800/Tape & Reel
MJB44H11T4G	D ² PAK (Pb-Free)	800/Tape & Reel
MJB45H11	D ² PAK	50 Units/Rail
MJB45H11G	D ² PAK (Pb-Free)	50 Units/Rail
MJB45H11T4	D ² PAK	800/Tape & Reel
MJB45H11T4G	D ² PAK (Pb-Free)	800/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic		mbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector–Emitter Sustaining Voltage (I _C = 30 mA, I _B = 0)		EO(sus)	80	-	-	Vdc
Collector Cutoff Current (V _{CE} = Rated V _{CEO} , V _{BE} = 0)		CES	-	_	10	μΑ
Emitter Cutoff Current (V _{EB} = 5 Vdc)		EBO	-	-	50	μΑ
ON CHARACTERISTICS	•			•		
Collector-Emitter Saturation Voltage (I _C = 8 Adc, I _B = 0.4 Adc)		E(sat)	-	-	1.0	Vdc
Base–Emitter Saturation Voltage (I _C = 8 Adc, I _B = 0.8 Adc)		BE(sat)	-	-	1.5	Vdc
DC Current Gain (V _{CE} = 1 Vdc, I _C = 2 Adc)		η _{FE}	60	-	-	-
DC Current Gain (V _{CE} = 1 Vdc, I _C = 4 Adc)			40	-	-	
DYNAMIC CHARACTERISTICS						
Collector Capacitance (V _{CB} = 10 Vdc, f _{test} = 1 MHz) MJB4 MJB4	4H11	Ccb	1 1	130 230	1 1	pF
Gain Bandwidth Product ($I_C = 0.5 \text{ Adc}$, $V_{CE} = 10 \text{ Vdc}$, $f = 20 \text{ MHz}$) MJB4 MJB4	4H11	f _T		50 40		MHz
SWITCHING TIMES						
Delay and Rise Times(I _C = 5 Adc, I _{B1} = 0.5 Adc) MJB4 MJB4	4H11	ı + t _r	- -	300 135	- -	ns
Storage Time($I_C = 5$ Adc, $I_{B1} = I_{B2} = 0.5$ Adc) MJB4 MJB4	4H11	t _s	-	500 500	- -	ns
Fall Time($I_C = 5$ Adc, $I_{B1} = I_{B2} = 0.5$ Adc) MJB4 MJB4		t _f	- -	140 100	- -	ns

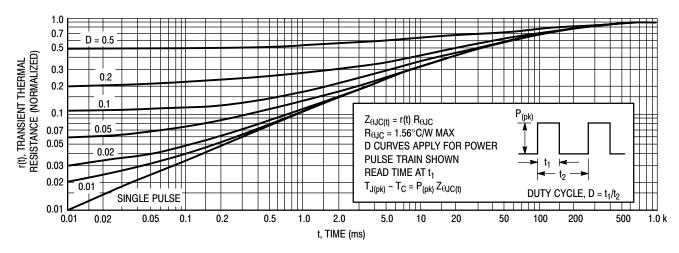


Figure 1. Thermal Response

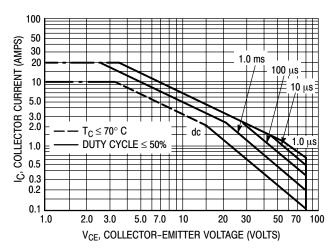


Figure 2. Maximum Rated Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 2 is based on $T_{J(pk)} = 150^{\circ}C$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 1. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

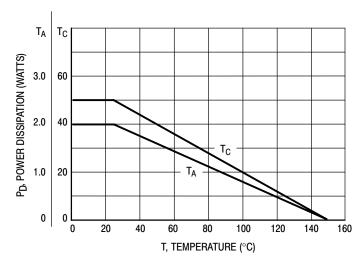


Figure 3. Power Derating

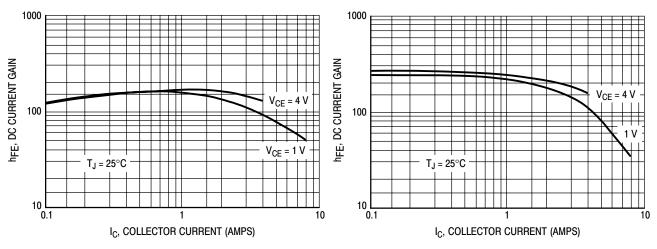


Figure 4. MJB44H11 DC Current Gain

Figure 5. MJB45H11 DC Current Gain

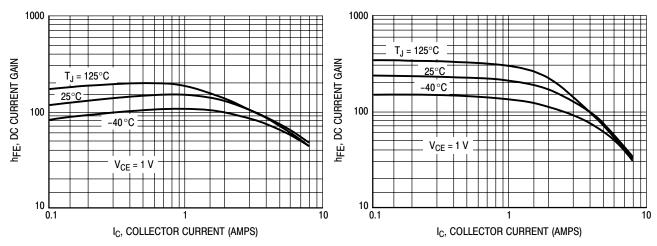


Figure 6. MJB44H11 Current Gain versus Temperature

Figure 7. MJB45H11 Current Gain versus Temperature

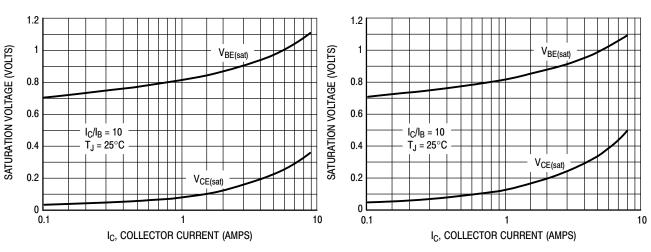
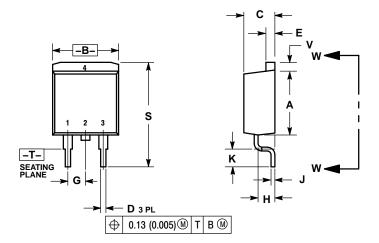


Figure 8. MJB44H11 On-Voltages

Figure 9. MJB45H11 On-Voltages

PACKAGE DIMENSIONS

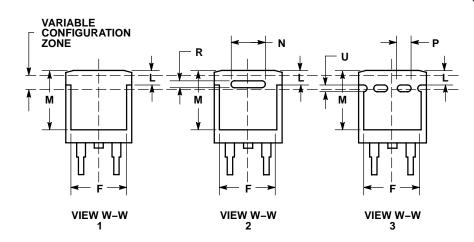
D²PAK 3 CASE 418B-04 **ISSUE J**



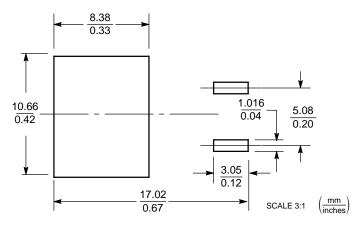
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

	INCHES		MILLIN	ETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.340	0.380	8.64	9.65	
В	0.380	0.405	9.65	10.29	
С	0.160	0.190	4.06	4.83	
D	0.020	0.035	0.51	0.89	
E	0.045	0.055	1.14	1.40	
F	0.310	0.350	7.87	8.89	
G	0.100	BSC	2.54	BSC	
Н	0.080	0.110	2.03	2.79	
J	0.018	0.025	0.46	0.64	
K	0.090	0.110	2.29	2.79	
L	0.052	0.072	1.32	1.83	
M	0.280	0.320	7.11	8.13	
N	0.197 REF		5.00 REF		
Р	0.079 REF 2.00 REF		REF		
R	0.039	0.039 REF 0.99 REF		REF	
S	0.575	0.625	14.60	15.88	
V	0.045	0.055	1.14	1.40	

- STYLE 1:
 PIN 1. BASE
 2. COLLECTOR
 3. EMITTER
 4. COLLECTOR



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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MJB44H11/D